# 3-Pin Voltage Supervisors with Active-High, Push-Pull Reset

Check for Samples: TLV810M, TLV810R, TLV810S, TLV810Z

### **FEATURES**

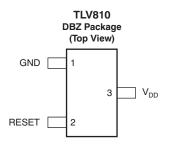
- 3-Pin SOT23 Package
- Supply Current: 9 µA (Typical)
- Precision Supply Voltage Monitor:
  2.5 V, 3 V, 3.3 V, 5 V
- Power-On Reset Generator with Fixed Delay Time of 200 ms
- Pin-for-Pin Compatible with MAX810
- Temperature Range: –40°C to +125°C
- Push-Pull, RESET Output

### **APPLICATIONS**

- DSPs, Microcontrollers, and Microprocessors
- · Wireless Communication Systems
- Portable/Battery-Powered Equipment
- Programmable Controls
- · Intelligent Instruments
- · Industrial Equipment
- Notebook and Desktop Computers
- Automotive Systems

#### **DEVICE FAMILY COMPARISON**

DEVICE	FUNCTION
TLV803	Open-Drain, RESET Output
TLV809	Push-Pull, RESET Output
TLV810	Push-Pull, RESET Output



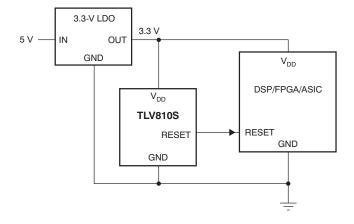
### DESCRIPTION

The TLV810 family of supervisory circuits provides circuit initialization and timing supervision, primarily for DSPs and processor-based systems.

During power-on, RESET is asserted when the supply voltage  $(V_{DD})$  becomes higher than 1.1 V. Thereafter, the supervisory circuit monitors  $V_{DD}$  and keeps RESET active as long as  $V_{DD}$  remains below the threshold voltage  $V_{IT}$ . An internal timer delays the return of the output to the inactive state (low) to ensure proper system reset. The delay time  $(t_{d(typ)} = 200 \text{ ms})$  starts after  $V_{DD}$  has risen above the threshold voltage,  $V_{IT}$ . When the supply voltage drops below the  $V_{IT}$  threshold voltage, the output becomes active (high) again. No external components are required. All the devices in this family have a fixed sense-threshold voltage  $(V_{IT})$  set by an internal voltage divider.

The product spectrum is designed for supply voltages of 2.5 V, 3 V, 3.3 V, and 5 V. The circuits are available in a 3-pin SOT-23 package. The TLV810 devices are characterized for operation over a temperature range of -40°C to +125°C.

#### TYPICAL APPLICATION





This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

# PACKAGE/ORDERING INFORMATION(1)

PRODUCT	THRESHOLD VOLTAGE	PACKAGE- LEAD	PACKAGE DESIGNATOR	SPECIFIED OPERATING TEMPERATURE	PACKAGE MARKING	ORDERING INFORMATION	TRANSPORT MEDIA, QUANTITY
TLV810Z	2.25 V	SOT23-3	DBZ	–40°C to +125°C	VOVQ	TLV810ZDBZR	Tape and Reel, 3000
ILVOIUZ	2.25 V	30123-3	DBZ	-40 C to +125 C	VOVQ	TLV810ZDBZT	Tape and Reel, 250
TLV810R	2.64 V	SOT23-3	DBZ	-40°C to +125°C	VOWO	TLV810RDBZR	Tape and Reel, 3000
ILVOIUR	2.04 V	50123-3	DBZ	-40 C t0 +125 C	VOWQ	TLV810RDBZT	Tape and Reel, 250
TLV810S	2.93 V	SOT23-3	DBZ	-40°C to +125°C	VOYO	TLV810SDBZR	Tape and Reel, 3000
12/8/05	2.93 V	50123-3	DBZ	-40 C t0 +125 C	VOXQ	TLV810SDBZT	Tape and Reel, 250
TI \/840M	4.20.1/	COTOO O	DD7	40°C to 1425°C	VOVO	TLV810MDBZR	Tape and Reel, 3000
TLV810M	4.38 V	SOT23-3 DBZ -40°C to +125°C		VOYQ	TLV810MDBZT	Tape and Reel, 250	

<sup>(1)</sup> For the most current package and ordering information, see the Package Option Addendum at the end of this data sheet, or visit the device product folders at www.ti.com.

### ABSOLUTE MAXIMUM RATINGS(1)

Over operating free-air temperature range (unless otherwise noted).

		VALUE		
		MIN	MAX	UNIT
\	V <sub>DD</sub> <sup>(2)</sup>	0	7	V
Voltage	All other pins <sup>(2)</sup>	-0.3	7	V
	Maximum low output current, I <sub>OL</sub>		5	mA
Current	Maximum high output current, I <sub>OH</sub>		<b>–</b> 5	mA
Current	Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0 or V <sub>I</sub> > V <sub>DD</sub> )		±20	mA
	Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0 or V <sub>O</sub> > V <sub>DD</sub> )		±20	mA
	Operating free-air temperature range, T <sub>A</sub>	-40	+125	°C
Temperature	Storage temperature range, T <sub>stg</sub>	-65	+150	°C
	Soldering temperature		+260	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### THERMAL INFORMATION

		TLV810		
	THERMAL METRIC <sup>(1)</sup>	DBZ	UNITS	
		3 PINS		
$\theta_{JA}$	Junction-to-ambient thermal resistance	286.9		
θ <sub>JCtop</sub>	Junction-to-case (top) thermal resistance	105.6		
θ <sub>JB</sub>	Junction-to-board thermal resistance	124.4	°C AA4	
₽JT	Junction-to-top characterization parameter	25.8	°C/W	
₽ <sub>ЈВ</sub>	Junction-to-board characterization parameter	107.9		
9 <sub>JCbot</sub>	Junction-to-case (bottom) thermal resistance	_		

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

<sup>(2)</sup> All voltage values are with respect to GND. For reliable operation the device should not be operated at 7 V for more than t = 1000h continuously.

## RECOMMENDED OPERATING CONDITIONS

At specified temperature range (unless otherwise noted).

		MIN	MAX	UNIT
$V_{DD}$	Supply voltage	1.1	6	V
T <sub>A</sub>	Operating free-air temperature range	-40	+125	°C

# **ELECTRICAL CHARACTERISTICS**

Over recommended operating free-air temperature range (unless otherwise noted).

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
			$V_{DD} = 2.0 \text{ V to 6 V}, I_{OH} = -500 \mu\text{A}$	V <sub>DD</sub> – 0.2			
V	High lovel output volto	<b></b>	$V_{DD} = 3.3 \text{ V}, I_{OH} = -2 \text{ mA}$	$V_{DD} - 0.4$			V
V <sub>OH</sub>	High-level output volta	ge	$V_{DD} = 6 \text{ V}, I_{OH} = -4 \text{ mA}, T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	$V_{DD} - 0.4$			
			$V_{DD} = 6 \text{ V}, I_{OH} = -4 \text{ mA}, T_A = +85^{\circ}\text{C to } +125^{\circ}\text{C}$	$V_{DD} - 0.5$			
			$V_{DD} = 2.5 \text{ V to 6 V}, I_{OL} = 500 \mu\text{A}$			0.2	
$V_{OL}$	Low-level output voltage	ge	V <sub>DD</sub> = 3.3 V, I <sub>OL</sub> = 2 mA			0.4	V
			$V_{DD} = 6 \text{ V}, I_{OL} = 4 \text{ mA}$			0.4	
	Power-up reset voltage	e <sup>(1)</sup>	$V_{OH} \ge V_{DD} - 0.2 \text{ V}, I_{OH} = -50  \mu\text{A}$	1.1			V
		TLV810Z		2.20	2.25	2.30	
V	Negative-going input	TLV810R		2.58	2.64	2.70	V
$V_{IT-}$	threshold voltage (2)	TLV810S		2.87	2.93	2.99	V
		TLV810M		4.28	4.38	4.48	
		TLV810Z			30		
V	Hyptoropia	TLV810R	L = 50 uA T = 125°C		35		m\/
$V_{hys}$	Hysteresis	steresis $I_{OH} = -50 \mu A, T_A = +25 ^{\circ} C$	$I_{OH} = -50 \ \mu A, I_A = +25 \ C$		40		mV
		TLV810M			60		
	Cumply ourrant		V <sub>DD</sub> = 2 V, output unconnected		9	15	
$I_{DD}$	Supply current	$V_{DD} = 6 \text{ V}$ , output unconnected			20	30	μA

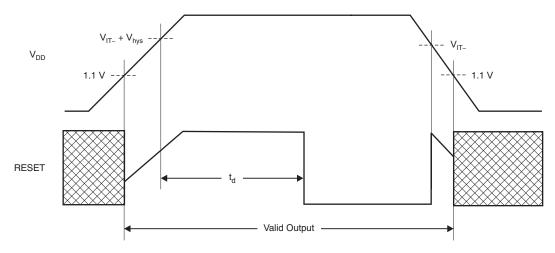
 <sup>(1)</sup> The lowest supply voltage at which RESET becomes valid. t<sub>r, VDD</sub> ≤ 66.7 ms/V.
 (2) To ensure best stability of the threshold voltage, a bypass capacitor ( 0.1-µF ceramic) should be placed near the supply terminals.

## **SWITCHING CHARACTERISTICS**

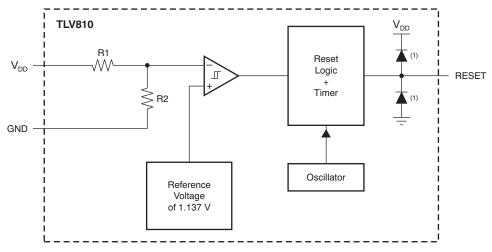
At  $T_A = +25$ °C, unless otherwise noted.

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t <sub>w</sub>	Pulse width at V <sub>DD</sub>	$V_{DD} = 1.08 V_{IT-}$ to 0.92 $V_{IT-}$		1		μs
t <sub>d</sub>	Delay time	V <sub>DD</sub> ≥ V <sub>IT</sub> + 0.2 V; see Timing Diagram	120	200	280	ms

# **TIMING DIAGRAM**



# **FUNCTIONAL BLOCK DIAGRAM**



(1) Parasitic diode.

### **TYPICAL CHARACTERISTICS**

At  $T_A$  = +25°C,  $V_{IT-}$  = 4.38 V, and  $V_{DD}$  = 5.0 V, unless otherwise noted.

# LOW-LEVEL OUTPUT VOLTAGE vs LOW-LEVEL OUTPUT CURRENT

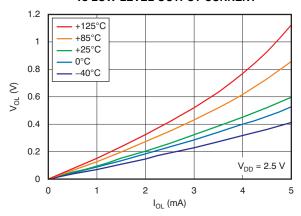


Figure 1.

# SUPPLY CURRENT vs SUPPLY VOLTAGE

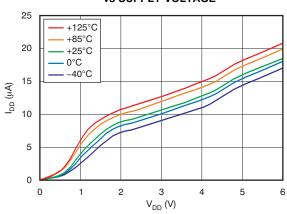


Figure 2.

# HIGH-LEVEL OUTPUT VOLTAGE vs HIGH-LEVEL OUTPUT CURRENT

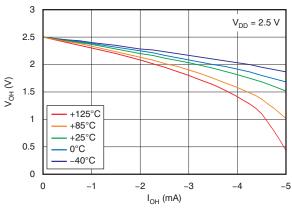


Figure 3.

# NORMALIZED INPUT THRESHOLD VOLTAGE vs free-air temperature at $v_{DD}$

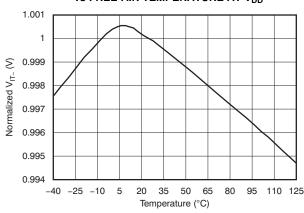
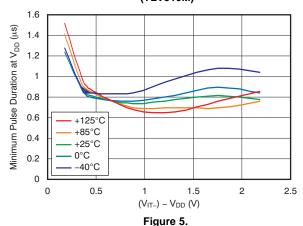


Figure 4.

# MINIMUM PULSE DURATION AT $V_{DD}$ vs $V_{DD}$ THRESHOLD OVERDRIVE VOLTAGE (TLV810M)



DELAY TIME vs TEMPERATURE

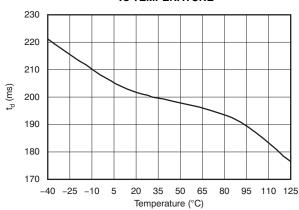


Figure 6.

#### **APPLICATION INFORMATION**

## **VDD TRANSIENT REJECTION**

The TLV810 has built-in rejection of fast transients on the  $V_{DD}$  pin. The rejection of transients depends on both the duration and the amplitude of the transient. The amplitude of the transient is measured from the bottom of the transient to the negative threshold voltage of the TLV810, as shown in Figure 7.

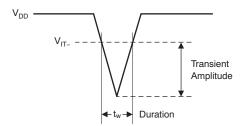


Figure 7. Voltage Transient Measurement

The TLV810 does not respond to transients that are fast duration/low amplitude or long duration/small amplitude. Figure 5 shows the relationship between the transient amplitude and the duration needed to trigger a reset. Any combination of duration and amplitude above the curve generates a reset signal.

### **RESET DURING POWER UP/DOWN**

The TLV810 output is valid when  $V_{DD}$  is greater than 1.1 V. When  $V_{DD}$  is less than 1.1 V, the output is undefined. Figure 8 shows a typical waveform for the power-up sequence.

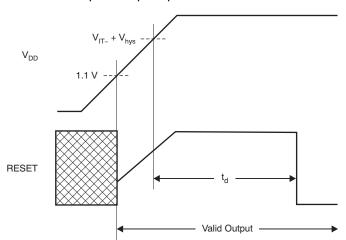


Figure 8. Power-Up Response

### **BIDIRECTIONAL RESET PINS**

Some microcontrollers have bidirectional reset pins that act as both inputs and outputs. In a situation where both the TLV810 and the microcontroller are attempting to drive the RESET line, a series resistor should be placed between the output of the TLV810 and the RESET pin of the microcontroller to protect against excessive current flow. Figure 9 shows the connection of the TLV810 to a microcontroller using a series resistor to drive a bidirectional RESET line.

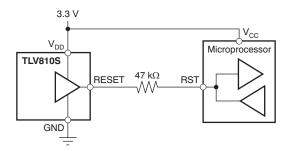


Figure 9. Connection to Bidirectional Reset Pin

#### PACKAGING INFORMATION

Orderable	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
part number	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
TLV810MDBZR	Active	Production	SOT-23 (DBZ)   3	3000   LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	VOYQ
TLV810MDBZT	Active	Production	SOT-23 (DBZ)   3	250   SMALL T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	VOYQ
TLV810RDBZR	Active	Production	SOT-23 (DBZ)   3	3000   LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	VOWQ
TLV810RDBZT	Active	Production	SOT-23 (DBZ)   3	250   SMALL T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	VOWQ
TLV810ZDBZR	Active	Production	SOT-23 (DBZ)   3	3000   LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	VOVQ

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

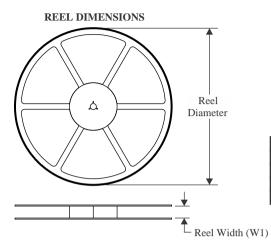
<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

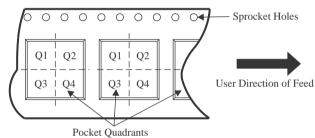
## TAPE AND REEL INFORMATION



# 

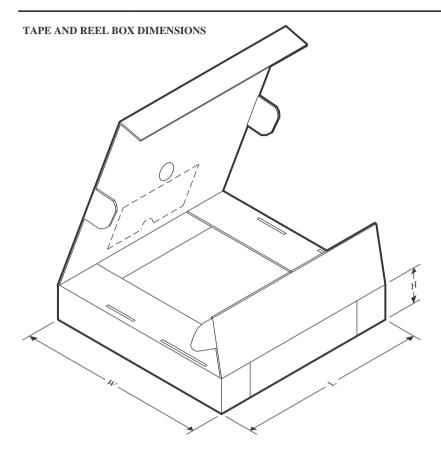
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV810MDBZR	SOT-23	DBZ	3	3000	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
TLV810MDBZT	SOT-23	DBZ	3	250	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
TLV810RDBZR	SOT-23	DBZ	3	3000	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
TLV810RDBZT	SOT-23	DBZ	3	250	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
TLV810ZDBZR	SOT-23	DBZ	3	3000	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3

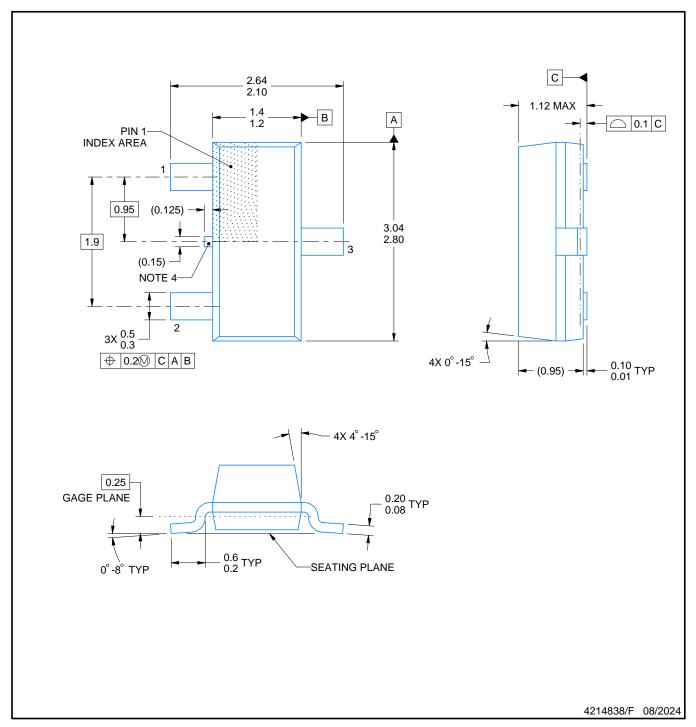


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV810MDBZR	SOT-23	DBZ	3	3000	200.0	183.0	25.0
TLV810MDBZT	SOT-23	DBZ	3	250	203.0	203.0	35.0
TLV810RDBZR	SOT-23	DBZ	3	3000	200.0	183.0	25.0
TLV810RDBZT	SOT-23	DBZ	3	250	200.0	183.0	25.0
TLV810ZDBZR	SOT-23	DBZ	3	3000	203.0	203.0	35.0



SMALL OUTLINE TRANSISTOR

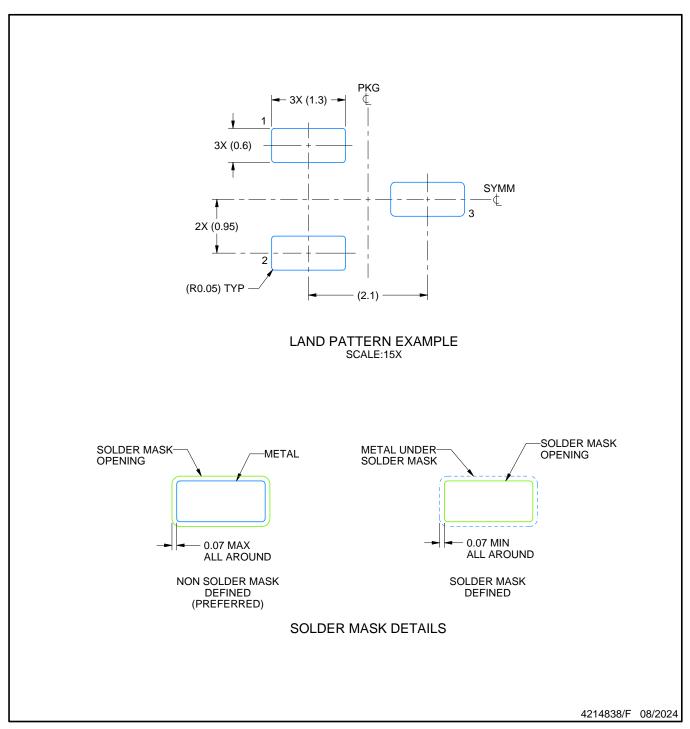


### NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  This drawing is subject to change without notice.
  Reference JEDEC registration TO-236, except minimum foot length.

- 4. Support pin may differ or may not be present.
- 5. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side

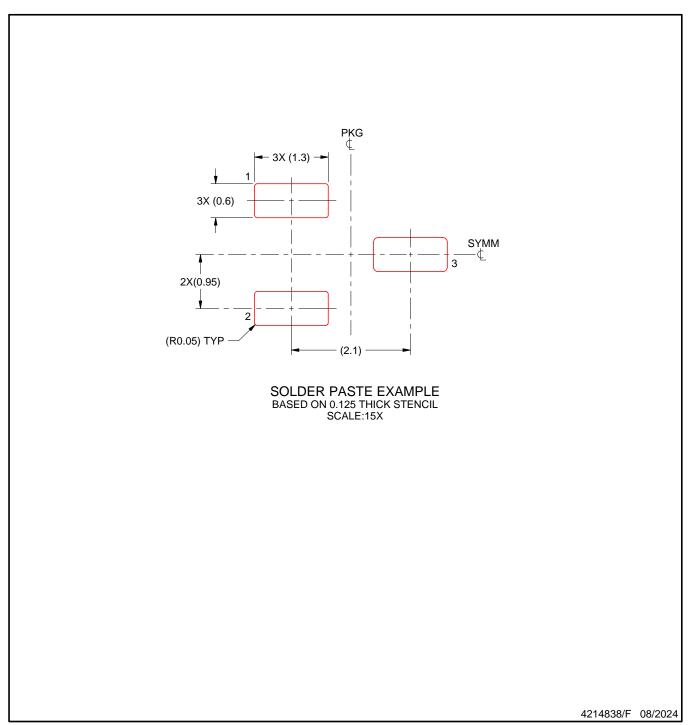
SMALL OUTLINE TRANSISTOR



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

<sup>7.</sup> Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

<sup>8.</sup> Board assembly site may have different recommendations for stencil design.